

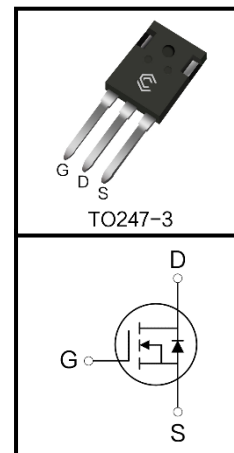
500V N-Channel MOSFET

FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information		
Device	Package	Marking
CS45N50FW	TO247-3	CS45N50FW

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, unless otherwise noted			
Parameter	Symbol	Value	Unit
Drain-Source Voltage ($V_{GS} = 0\text{V}$)	V_{DSS}	500	V
Continuous Drain Current	I_D	45	A
Pulsed Drain Current (note1)	I_{DM}	180	A
Gate-Source Voltage	V_{GSS}	± 30	V
Single Pulse Avalanche Energy (note2)	E_{AS}	1901	mJ
Avalanche Current (note1)	I_{AS}	19.5	A
Repetitive Avalanche Energy (note1)	E_{AR}	0.76	mJ
Power Dissipation ($T_C = 25^\circ\text{C}$)	P_D	961	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	$-55 \sim +150$	$^\circ\text{C}$

Thermal Resistance			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R_{thJC}	0.13	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	R_{thJA}	62.5	

Specifications $T_J = 25^\circ\text{C}$, unless otherwise noted						
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	500	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 500V, V_{GS} = 0V, T_J = 25^\circ\text{C}$	--	--	1	μA
Gate-Source Leakage	I_{GSS}	$V_{GS} = \pm 30V$	--	--	± 100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	3	3.5	4	V
Drain-Source On-Resistance(Note3)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 22.5A$	--	85	100	m Ω
Dynamic						
Input Capacitance	C_{ISS}	$V_{GS} = 0V,$ $V_{DS} = 25V,$ $f = 250\text{kHz}$	--	7705	--	pF
Output Capacitance	C_{OSS}		--	710	--	
Reverse Transfer Capacitance	C_{RSS}		--	12	--	
Internal Gate Resistance	R_g		--	1.4	--	
Total Gate Charge	Q_g	$V_{DD} = 300V, I_D = 22.5A,$ $V_{GS} = 10V$	--	128	--	nC
Gate-Source Charge	Q_{gs}		--	32	--	
Gate-Drain Charge	Q_{gd}		--	41	--	
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 250V, I_D = 22.5A,$ $R_G = 25\Omega$	--	117	--	ns
Turn-on Rise Time	t_r		--	68	--	
Turn-off Delay Time	$t_{d(off)}$		--	65	--	
Turn-off Fall Time	t_f		--	7	--	
Drain-Source Body Diode Characteristics						
Continuous Body Diode Current	I_S	$T_C = 25^\circ\text{C}$	--	--	45	A
Pulsed Diode Forward Current	I_{SM}		--	--	180	
Body Diode Voltage	V_{SD}	$T_J = 25^\circ\text{C}, I_{SD} = 22.5A, V_{GS} = 0V$	--	--	1.4	V
Reverse Recovery Time	t_{rr}	$V_{DD} = 250V, I_S = 22.5A,$ $di_F/dt = 100A / \mu\text{s}$	--	403	--	ns
Reverse Recovery Charge	Q_{rr}		--	7.5	--	μC

Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. $L = 10.0\text{mH}, V_{DD} = 70V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
3. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty Cycle $\leq 1\%$

Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 1. Output Characteristics ($T_J = 25^\circ\text{C}$)

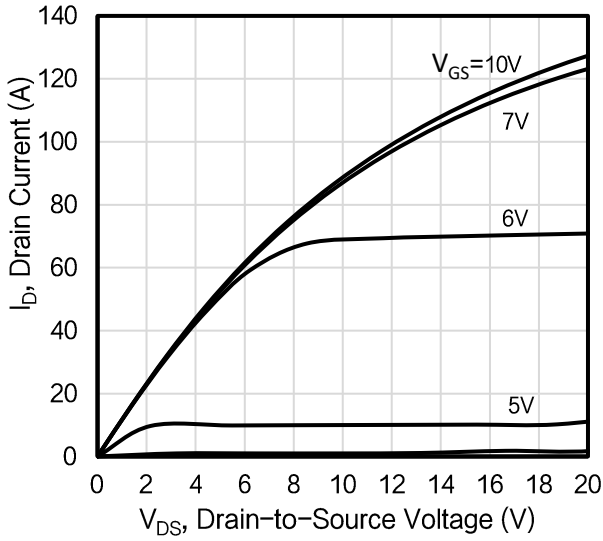


Figure 2. Body Diode Forward Voltage

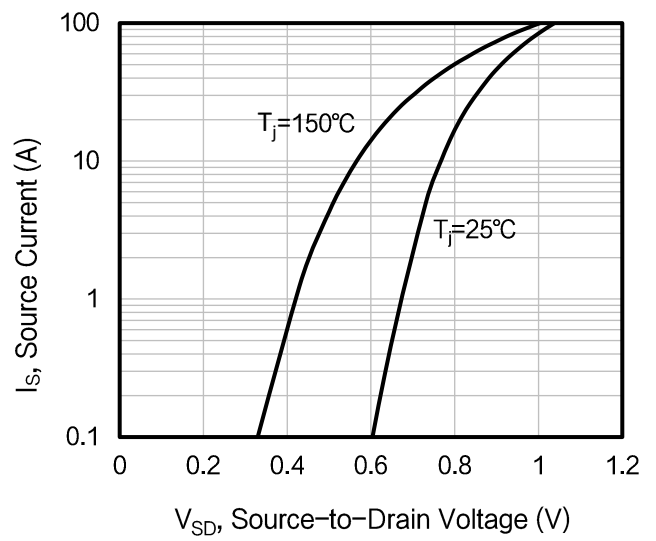


Figure 3. Drain Current vs. Temperature

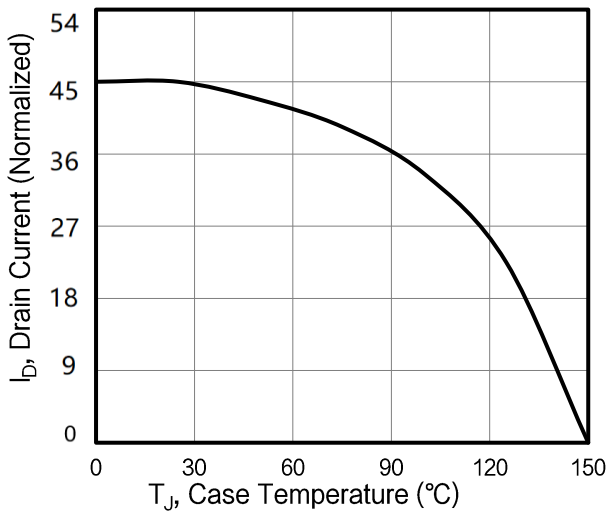


Figure 4. BV_{DSS} Variation vs. Temperature

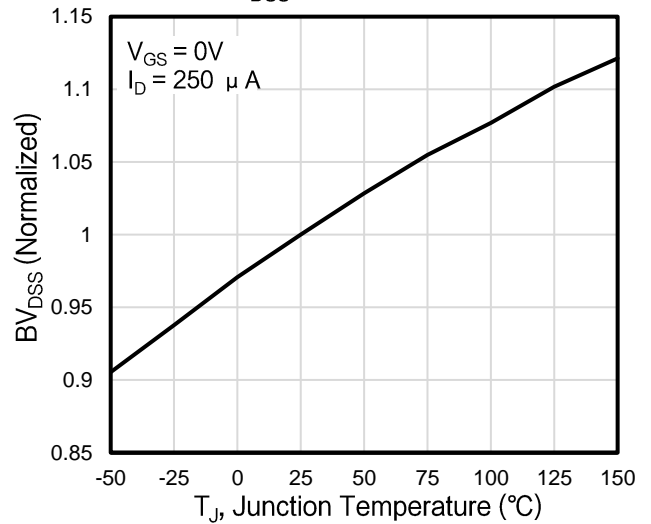


Figure 5. Transfer Characteristics

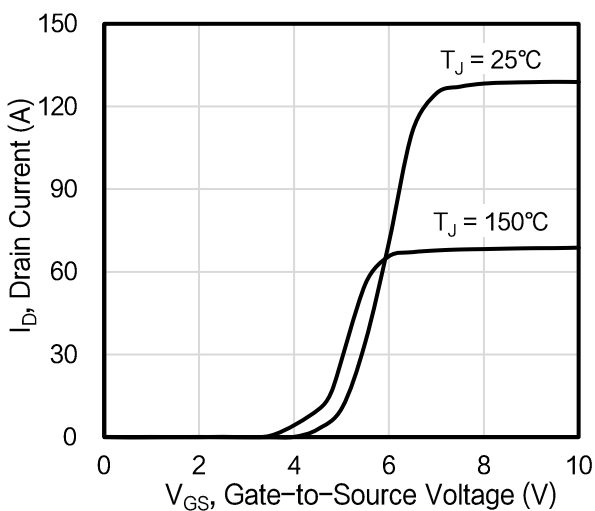
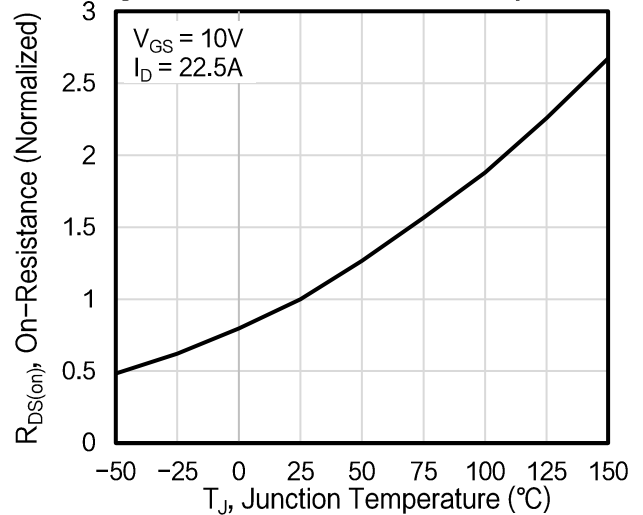


Figure 6. On-Resistance vs. Temperature



Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 7. Capacitance

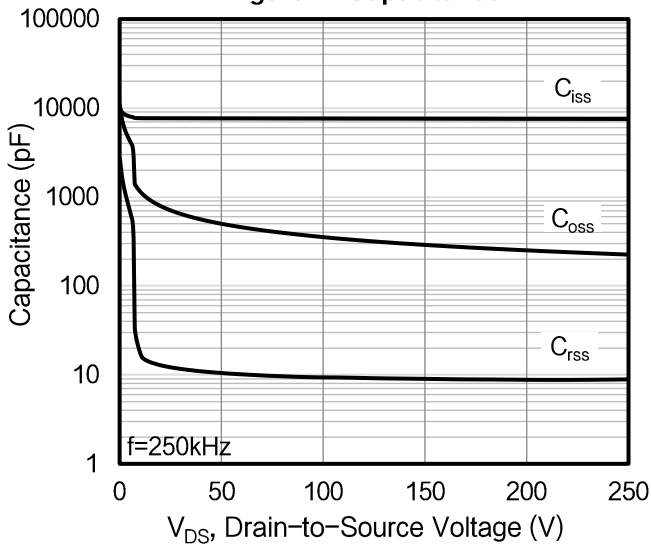


Figure 8. Gate Charge

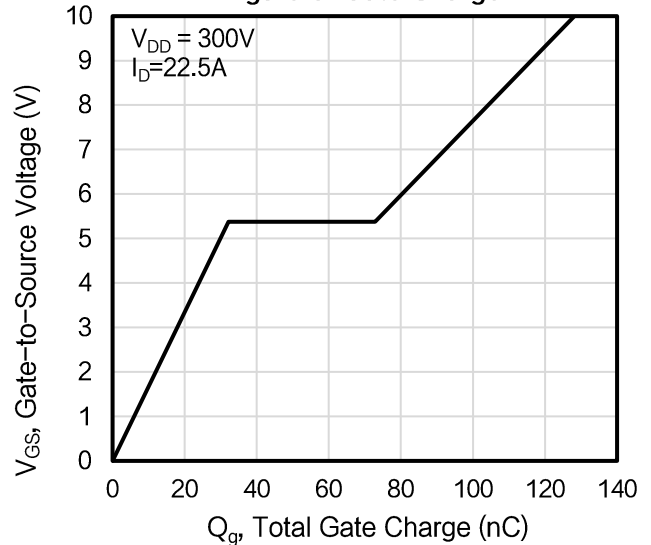


Fig.9 Threshold Voltage vs. Temperature

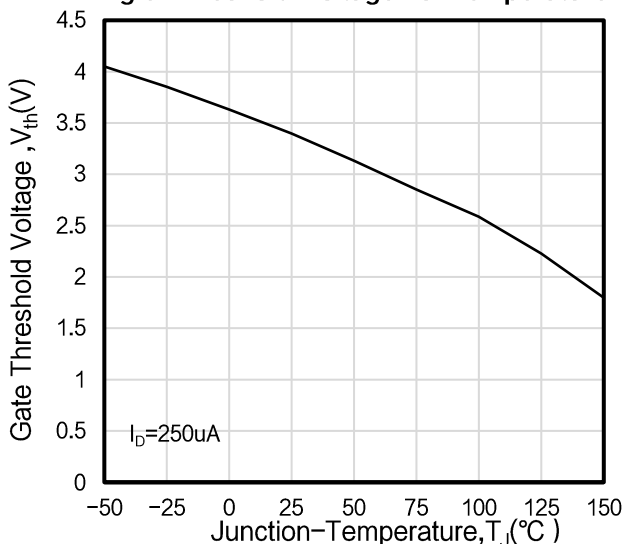


Figure 10. Transient Thermal Impedance

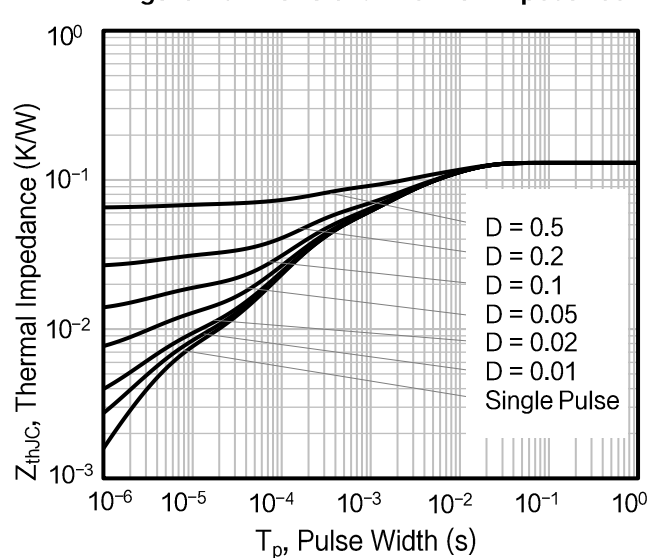


Fig.11 Safe Operating Area

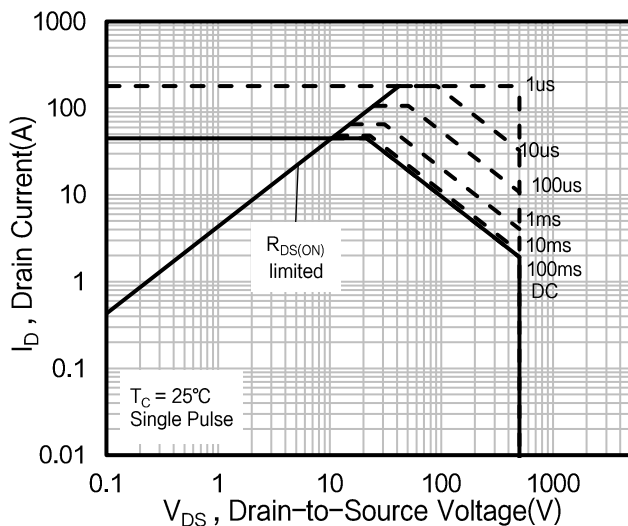
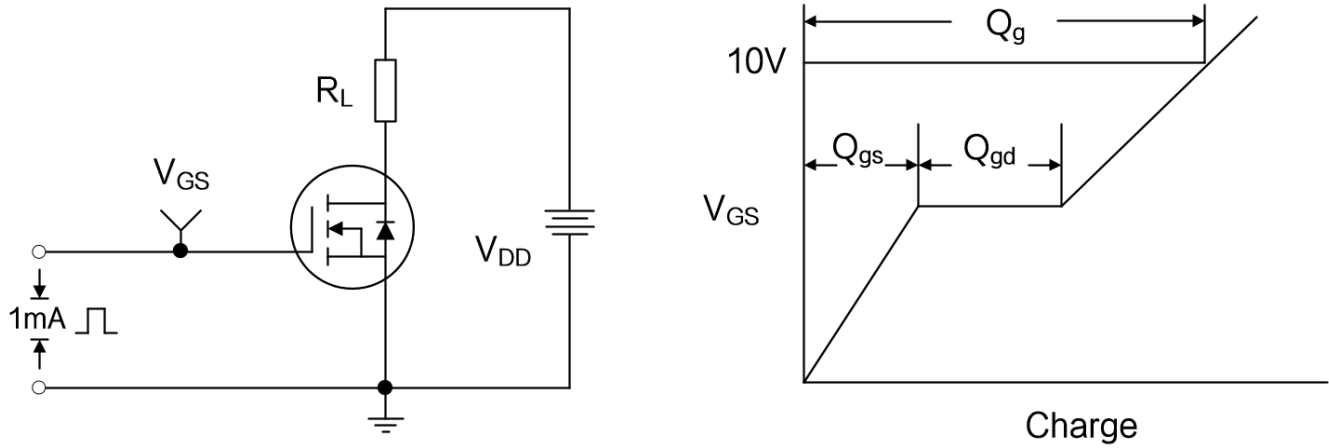
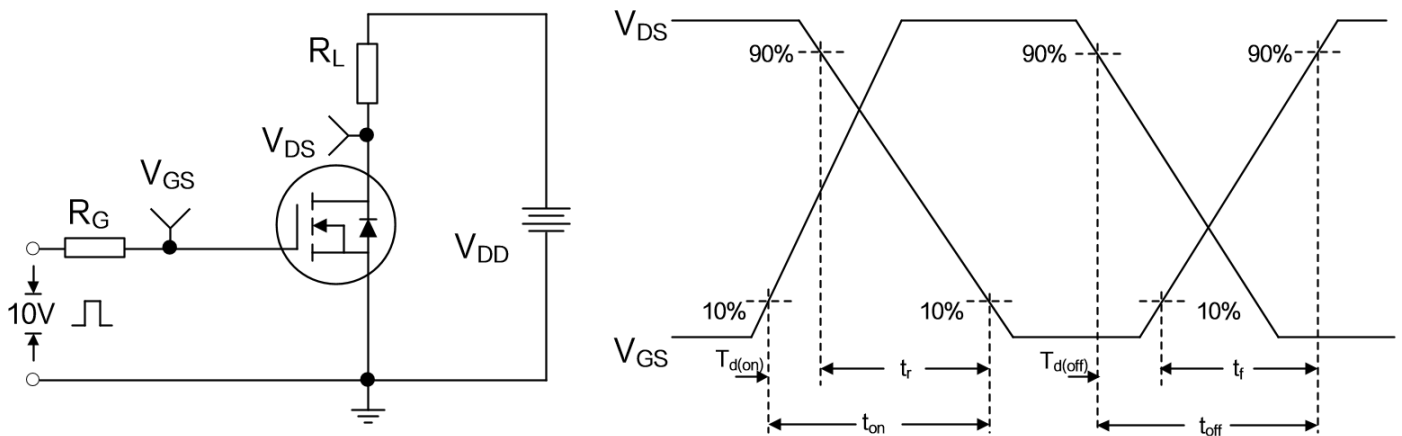
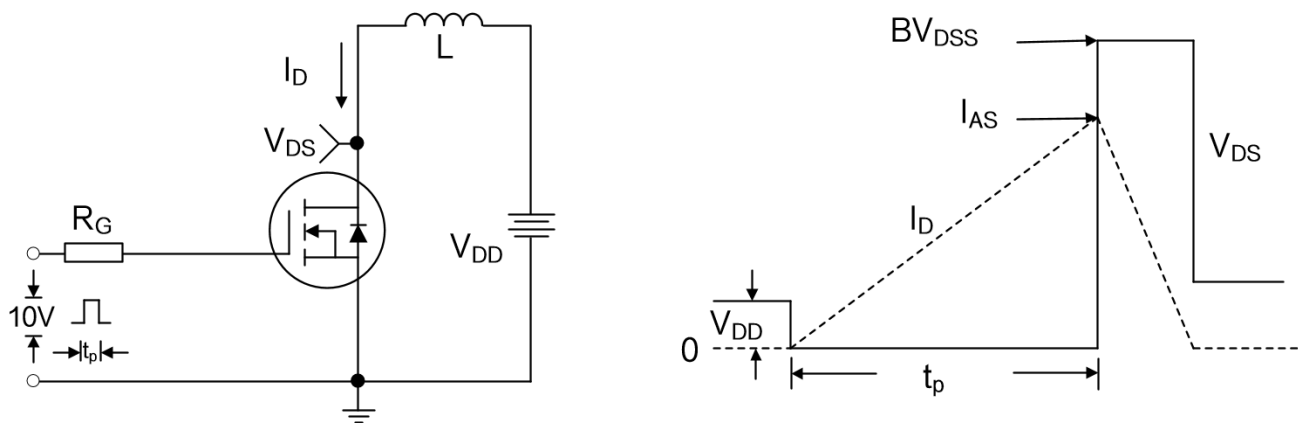
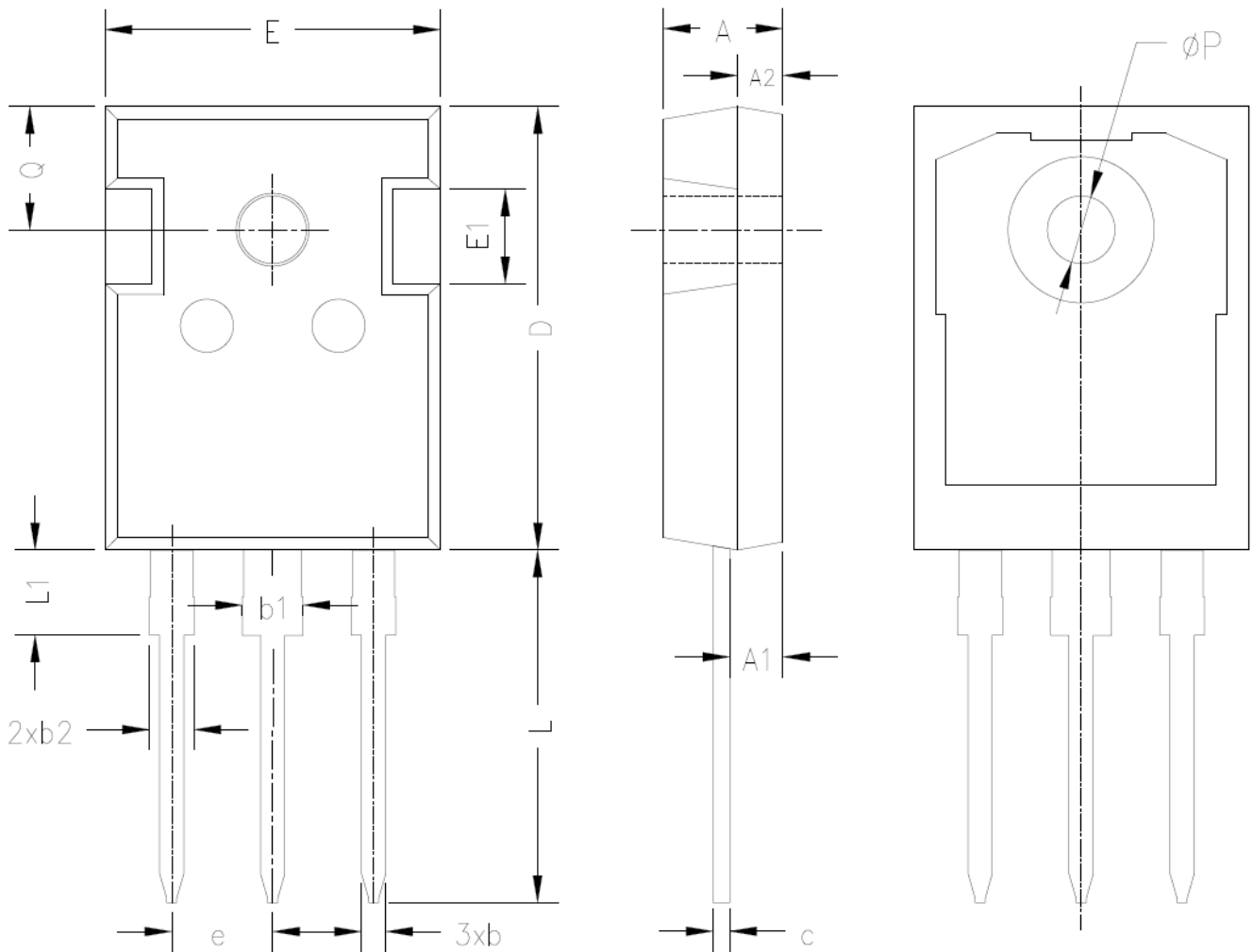


Figure A: Gate Charge Test Circuit and Waveform

Figure B: Resistive Switching Test Circuit and Waveform

Figure C: Unclamped Inductive Switching Test Circuit and Waveform


TO247-3



SYMBOLS	MILLIMETERS	
	MIN	MAX
A	4.80	5.30
A1	2.20	2.60
A2	1.85	2.16
b	1.00	1.40
b1	2.85	3.38
b2	1.90	2.41
c	0.45	0.75
D	20.80	21.30
E	15.20	16.20
E2	3.68	5.20
e	5.44BCS	
L	19.50	20.50
L1	3.90	4.50
Q	5.65	6.35
ΦP	3.30	3.90

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